



M T B F (E I A J R C R - 9 1 0 2)

Model	SNDHS200A12
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	0	0.0000	
2		Hybrid	0	0.0000	
3	Transistors		0	0.0000	
4	Diodes		0	0.0000	
5	LED•Optocouplers		0	0.0000	
6	Resistors		5	0.1066	
7	Capacitors		11	0.1745	
8	Transformer•Choke Coil		1	0.0230	
9	Connectors		200	0.1998	
10	Others		7	3.1226	included DHS200A12
Total Failure Rate [10 ⁻⁶ /H]				3.6265	

M T B F [H]	276,000
Ambient Temperature [℃]	—
Load Factor [%]	—